

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	(substrate and (gate with (insulator or dielectric)) and (first with mold) and etch\$3 and (opening or trench or via or mesa or hole or cavity) and (first with metal with gate) and (second with mold) and (secondt with metal with gate) and (work adj function)).CLM.	US-PGPUB	OR	ON	2005/09/27 17:33
L2	0	(substrate and (gate with (insulator or dielectric)) and (first with mold) and etch\$3 and (opening or trench or via or mesa or hole or cavity) and (first with metal with gate) and (second with mold) and (secondt with metal with gate)).CLM.	US-PGPUB	OR	ON	2005/09/27 17:33
L3	1	(substrate and (gate with (insulator or dielectric)) and (first with mold) and etch\$3 and (opening or trench or via or mesa or hole or cavity) and (first with metal with gate) and (second with mold) and (second with metal with gate)).CLM.	US-PGPUB	OR	ON	2005/09/27 17:33
L4	1	(substrate and (gate with (insulator or dielectric)) and (first with mold) and etch\$3 and (opening or trench or via or mesa or hole or cavity) and (first with metal with gate) and (second with mold) and (second with metal with gate) and (work adj function)).CLM.	US-PGPUB	OR	ON	2005/09/27 17:33